TOSHIBA SH400R32B

TOSHIBA ALLOY-FREE HIGHT SPEED THYRISTOR

SH400R32B

HIGH POWER CONTROL APPLICATIONS

• Repetitive Peak Off-State Voltage : V_{DRM} = 1300V

• Repetitive Peak Reverse Voltage: VRRM

• Average On-State Current : $I_{T(AV)} = 400A$

• Turn-Off Time : $t_q = 25 \mu s$ (Max.)

• Critical Rate of Rise of On-State Current

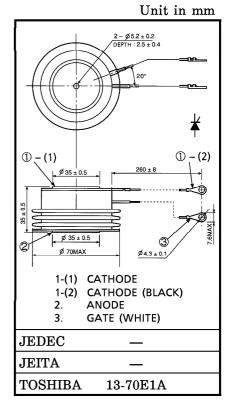
: $di/dt = 200A/\mu s$

• Critical Rate of Rise of Off-State Voltage

: $dv/dt = 500V/\mu s$

• Weight : 480g

Flat Package



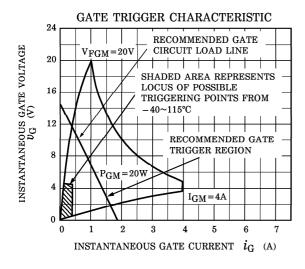
MAXIMUM RATINGS

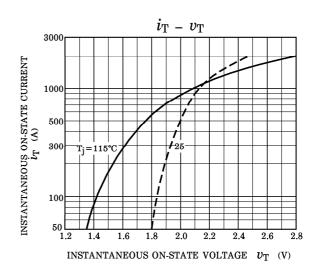
CHARACTERISTIC	SYMBOL	SYMBOL	RATING	UNIT
Repetitive Peak Off-State Voltage and Repetitive Peak Reverse Voltage	V _{DRM} V _{RRM}	$v_{ m DRM} \ v_{ m RRM}$	1300	V
Non-Repetitive Peak Reverse Voltage (Non-Repetitive $< 5 \text{ms}, T_j = 0 \sim 115^{\circ}\text{C}$)	v_{RSM}	$v_{ m RSM}$	1400	V
R.M.S On-State Current	I _T (RMS)	I _T (RMS)	630	Α
Average On-State Current	I _T (AV)	I _T (AV)	400	Α
Peak One Cycle Surge On-State Current (Non-Repetitive)	I_{TSM}	I_{TSM}	8000 (50Hz) 8800 (60Hz)	A
I ² t Limit Value	${ m I}^2{ m t}$	${f I^2 t}$	3.2×10^{5}	A^2s
Critical Rate of Rise of On-State Current (Note)	di / dt	di / dt	200	A/μs
Peak Gate Power Dissipation	P _{GM}	P _{GM}	20	W
Average Gate Power Dissipation	PG (AV)	P _G (AV)	4	W
Peak Forward Gate Current	$I_{\mathbf{GM}}$	$\mathbf{I}_{\mathbf{GM}}$	4	Α
Peak Forward Gate Voltage	v_{FGM}	v_{FGM}	20	V
Peak Reverse Gate Voltage	v_{RGM}	v_{RGM}	5	V
Junction Temperature	T_{j}	T_{j}	-40~115	$^{\circ}\mathrm{C}$
Storage Temperature Range	$\mathrm{T_{stg}}$	$\mathrm{T_{stg}}$	-40~115	$^{\circ}\mathrm{C}$
Mounting Force	_	_	14.7 ± 1.5	kN

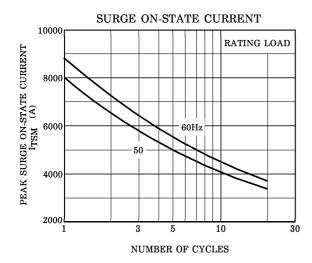
Note : V_D=650V, f=50Hz, T_j=110°C, Gate Supply (V_G=15V, R_G=8\Omega, t_r \le 1 \mu s)

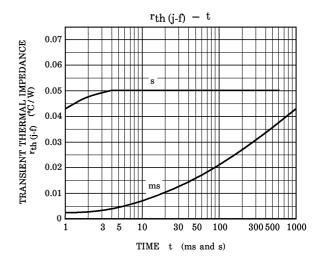
ELECTRICAL CHARACTERISTICS

CHARACTERISTIC	SYMBOL	TEST CONDITI	MIN.	MAX.	UNIT	
Repetitive Peak Off-State Current and Repetitive Peak Reverse Current	I _{DRM} I _{RRM}	$V_{ m DRM} = V_{ m RRM} = 1300 V$ $T_{ m j} = 115 { m ^{\circ} C}$		_	50	mA
Peak On-State Voltage	V_{TM}	$I_{TM} = 1250A, T_j = 25^{\circ}C$	_	2.2	V	
Gate Trigger Voltage	v_{GT}	l	$T_j = -40$ °C $T_j = 25$ °C	_	4.5 3.5	V
Gate Trigger Current	I_{GT}		$T_j = -40^{\circ}C$ $T_j = 25^{\circ}C$	_	400 260	mA
Gate Non-Trigger Voltage	$v_{ m GD}$	17- CEO17 TD 11590		0.2	_	V
Gate Non-Trigger Current	I_{GD}	$V_D = 650V, T_j = 115^{\circ}C$	5		mA	
Delay Time	^t d	$V_D = 650V, T_j = 25^{\circ}C$	_	4	μs	
Gate Turn-On Time	t_{gt}	Gate Supply $(V_G=15V, R_G=8\Omega,$		6	μs	
Turn-Off Time	t_q	I_{T} =800A, V_{R} \geq 50V dv / dt = 20V / μ s, T_{j} =1 V_{DRM} =650V	_	25	μs	
Holding Current	$I_{ m H}$	$T_j=25$ °C, $R_L=6\Omega$		400	mA	
Critical Rate of Rise of Off-State Voltage	dv / dt	V _{DRM} =870V, T _j =115 Gate Open, Exponentia	500	_	V/μs	
Thermal Resistance (Junction to Case)	$ m R_{th~(j-f)}$	DC	_	0.05	°C/W	









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